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November 2013

FQPF2N70

N-Channel QFET® MOSFET

700 V, 2.0 A, 6.3 Ω

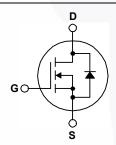
Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.

Features

- 2.0 A, 700 V, $R_{DS(on)}$ = 6.3 Ω (Max.) @ V_{GS} = 10 V, I_D = 1.0 A
- Low Gate Charge (Typ. 9 nC)
- · Low Crss (Typ. 5 pF)
- 100% Avalanche Tested





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol		Parameter	FQPF2N70	Unit	
V_{DSS}	Drain-Source Voltage		700	V	
I _D	Drain Current	- Continuous (T _C = 25°C)	2.0*	Α	
		- Continuous (T _C = 100°C)	1.3*	Α	
I _{DM}	Drain Current	- Pulsed (Note	1) 8.0*	Α	
V _{GSS}	Gate-Source Voltage	Gate-Source Voltage			
E _{AS}	Single Pulsed Avalanche Energ	2) 140	mJ		
I _{AR}	Avalanche Current	1) 2.0	Α		
E _{AR}	Repetitive Avalanche Energy	Repetitive Avalanche Energy (Note 1)			
dv/dt	Peak Diode Recovery dv/dt	(Note	3) 4.5	V/ns	
P_{D}	Power Dissipation	(T _C = 25°C)	28	W	
Power Dissipation	- Derate Above 25°C	0.22	W/°C		
T _J , T _{STG}	Operating and Storage Tempera	-55 to +150	°C		
T _L	Maximum Lead Temperature fo	r Soldering, 1/8" from Case for 5 seconds	300	°C	

^{*}Drain current limited by maximum junction temperature.

Thermal Characteristics

Symbol	Parameter	FQPF2N70	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	4.46	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	C/VV

S

2.45

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQPF2N70	FQPF2N70	TO-220F	Tube	N/A	N/A	50 units

Electrical Characteristics $T_C = 25$ °C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	700			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I_D = 250 μ A, Referenced to 25°C		0.4		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 700 V, V _{GS} = 0 V			10	μΑ
	Zero Gate voltage Drain Current	V _{DS} = 560 V, T _C = 125°C			100	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30 V, V _{DS} = 0 V		-	100	nA
I_{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -30 V, V _{DS} = 0 V			-100	nA
On Cha	aracteristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0		5.0	V
R _{DS(on)}	Static Drain-Source	V _{GS} = 10 V, I _D = 1.0 A		5.0	6.3	Ω

Dynamic Characteristics

 g_{FS}

On-Resistance

Forward Transconductance

C _{iss}	Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V,		270	350	pF
Coss	Output Capacitance	f = 1.0 MHz	-	38	50	pF
C _{rss}	Reverse Transfer Capacitance		-	5	7	pF

 $V_{DS} = 50 \text{ V}, I_{D} = 1.0 \text{ A}$

Switching Characteristics

t _{d(on)}	Turn-On Delay Time					30	ns
t _r	Turn-On Rise Time	$V_{DD} = 350 \text{ V}, I_{D} = 2.0 \text{ A},$				80	ns
t _{d(off)}	Turn-Off Delay Time	$R_G = 25 \Omega$		/		50	ns
t _f	Turn-Off Fall Time	((Note 4)	/		70	ns
Q_g	Total Gate Charge	V _{DS} = 560 V, I _D = 2.0 A,			8.1	11	nC
$\frac{Q_g}{Q_gs}$	Gate-Source Charge	V _{GS} = 10 V		/	1.7		nC
Q_{gd}	Gate-Drain Charge		(Note 4)		4.4	-	nC

Drain-Source Diode Characteristics and Maximum Ratings

Is	Maximum Continuous Drain-Source Diode Forward Current				2.0	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				8.0	Α
V _{SD}	Drain-Source Diode Forward Voltage	-		1.4	V	
t _{rr}	Reverse Recovery Time	$V_{GS} = 0 \text{ V, I}_{S} = 2.0 \text{ A,}$	-	260		ns
Q _{rr}	Reverse Recovery Charge	dI _F / dt = 100 A/μs		1.09		μС

- 1. Repetitive rating : pulse-width limited by maximum junction temperature.
- 2. L = 45 mH, I_{AS} = 2.0 A, V_{DD} = 50 V, R_G = 25 Ω , starting T_J = 25°C.
- 3. $I_{SD} \leq$ 2.0 A, di/dt \leq 200 A/ μ s, $V_{DD} \leq$ BV $_{DSS}$, starting T_J = 25°C.
- Essentially independent of operating temperature.

Typical Characteristics

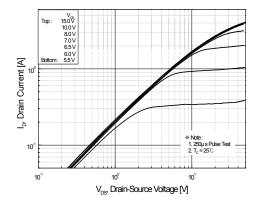


Figure 1. On-Region Characteristics

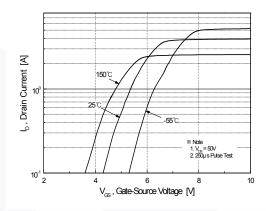


Figure 2. Transfer Characteristics

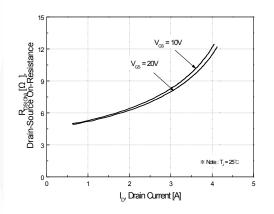


Figure 3. On-Resistance Variation vs.
Drain Current and Gate Voltage

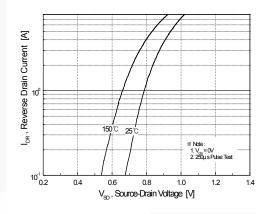


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

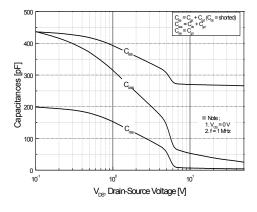


Figure 5. Capacitance Characteristics

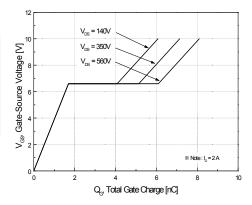


Figure 6. Gate Charge Characteristics

Typical Characteristics (continued)

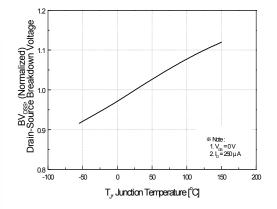


Figure 7. Breakdown Voltage Variation vs. Temperature

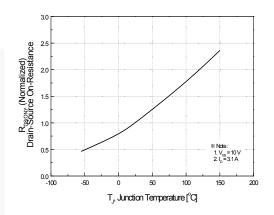


Figure 8. On-Resistance Variation vs. Temperature

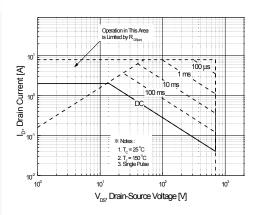


Figure 9. Maximum Safe Operating Area

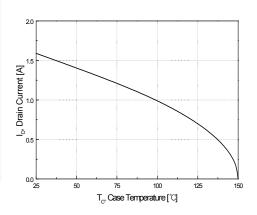


Figure 10. Maximum Drain Current vs. Case Temperature

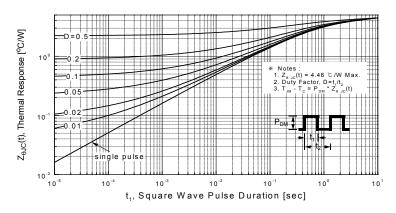


Figure 11. Transient Thermal Response Curve

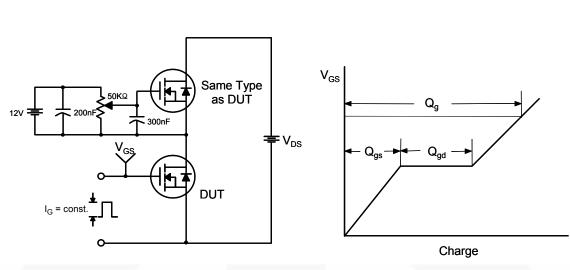


Figure 12. Gate Charge Test Circuit & Waveform

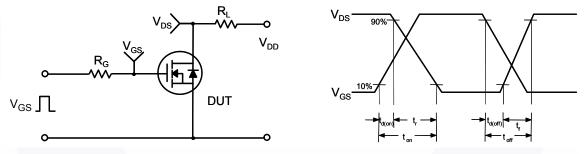


Figure 13. Resistive Switching Test Circuit & Waveforms

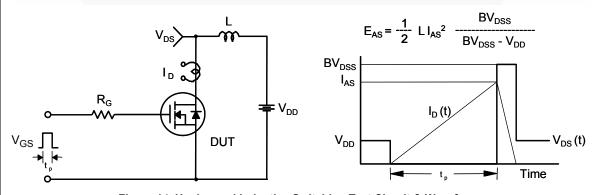
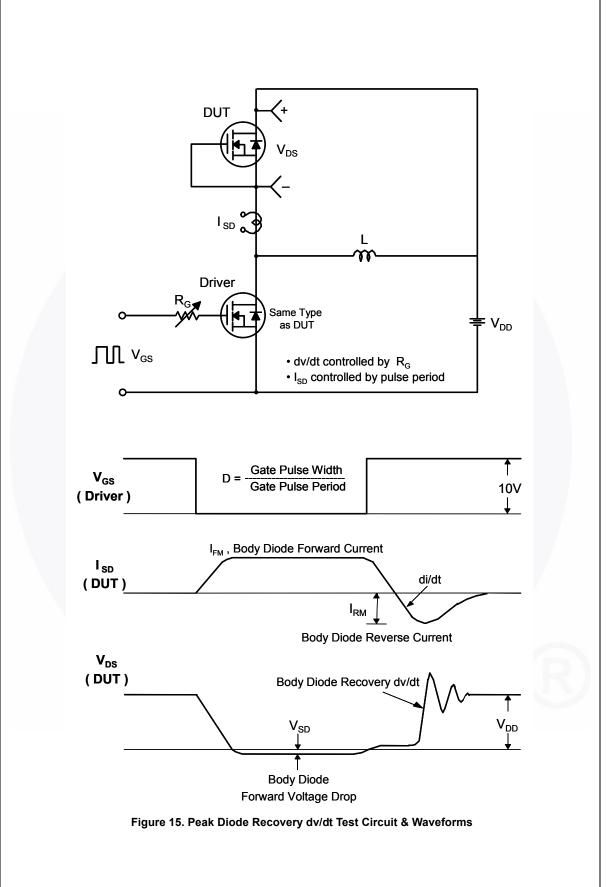


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



Mechanical Dimensions

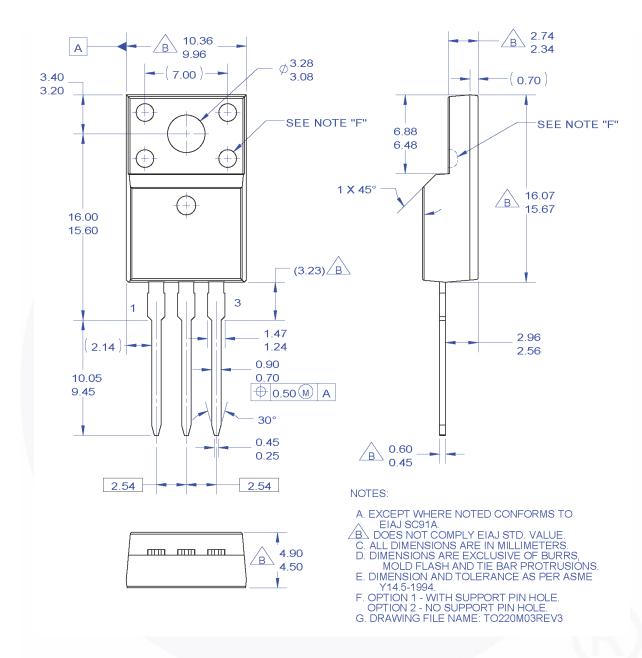


Figure 16. TO220, Molded, 3-Lead, Full Pack, EIAJ SC91, Straight Lead

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